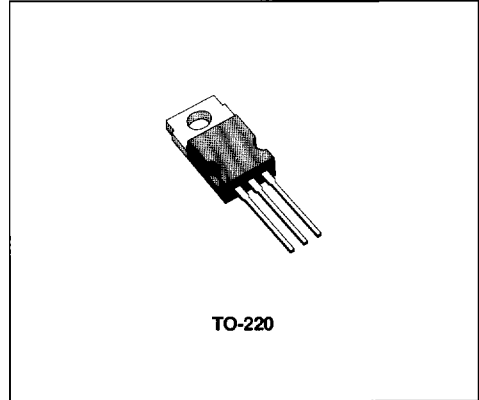


## POWER DARLINGTON TRANSISTORS

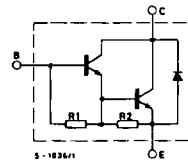
### DESCRIPTION

The 2N6386, 2N6387 and 2N6388 are silicon epitaxial-base NPN transistors in monolithic Darling-ton configuration and are mounted in Jedec TO-220 plastic package.

They are intended for use in low and medium fre-quency power applications.



### INTERNAL SCHEMATIC DIAGRAM



R1 Typ. 10k $\Omega$   
 R2 Typ. 150 $\Omega$

### ABSOLUTE MAXIMUM RATINGS

| Symbol    | Parameter   | 2N6386      | 2N6387 | 2N6388 | Unit       |
|-----------|---|-------------|--------|--------|------------|
| $V_{CBO}$ | Collector-base Voltage ( $I_B = 0$ )                  | 40          | 60     | 80     | V          |
| $V_{CEV}$ | Collector-emitter Voltage ( $V_{BE} = -1.5V$ )        | 40          | 60     | 80     | V          |
| $V_{CER}$ | Collector-emitter Voltage ( $R_{BE} \leq 100\Omega$ ) | 40          | 60     | 80     | V          |
| $V_{CEO}$ | Collector-emitter Voltage ( $I_B = 0$ )               | 40          | 60     | 80     | V          |
| $V_{EBO}$ | Emitter-base Voltage ( $I_C = 0$ )                    | 5           | 5      | 5      | V          |
| $I_C$     | Collector Current                                     | 8           | 10     | 10     | A          |
| $I_{CM}$  | Collector Peak Current                                | 15          |        |        | A          |
| $I_B$     | Base Current  | 250         |        |        | mA         |
| $P_{lot}$ | Total Power Dissipation at $T_{case} \leq 25^\circ C$ | 65          |        |        | W          |
| $T_{stg}$ | Storage Temperature                                   | - 65 to 150 |        |        | $^\circ C$ |
| $T_j$     | Junction Temperature                                  | 150         |        |        | $^\circ C$ |

**THERMAL DATA**

|                  |                                  |     |      |      |
|------------------|----------------------------------|-----|------|------|
| $R_{th\ j-case}$ | Thermal Resistance Junction-case | Max | 1.92 | °C/W |
|------------------|----------------------------------|-----|------|------|

**ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25^{\circ}C$  unless otherwise specified)

| Symbol           | Parameter  | Test Conditions   | Min.                       | Typ. | Max.                             | Unit                             |
|------------------|--|---|----------------------------|------|----------------------------------|----------------------------------|
| $I_{CEV}$        | Collector Cutoff Current<br>( $V_{BE} = -1.5V$ )                 | $V_{CE} = 40V$ for <b>2N6386</b><br>$V_{CE} = 60V$ for <b>2N6387</b><br>$V_{CE} = 80V$ for <b>2N6388</b><br>$T_{case} = 125^{\circ}C$<br>$V_{CE} = 40V$ for <b>2N6386</b><br>$V_{CE} = 60V$ for <b>2N6387</b><br>$V_{CE} = 80V$ for <b>2N6388</b> |                            |      | 0.3<br>0.3<br>0.3<br>3<br>3<br>3 | mA<br>mA<br>mA<br>mA<br>mA<br>mA |
| $I_{CEO}$        | Collector Cutoff Current<br>( $I_B = 0$ )                        | $V_{CE} = 40V$ for <b>2N6386</b><br>$V_{CE} = 60V$ for <b>2N6387</b><br>$V_{CE} = 80V$ for <b>2N6388</b>  |                            |      | 1<br>1<br>1                      | mA<br>mA<br>mA                   |
| $I_{EBO}$        | Emitter-base Current<br>( $I_C = 0$ )                            | $V_{EB} = 5V$   |                            |      | 5                                | mA                               |
| $V_{CEO(sus)}^*$ | Collector-emitter Sustaining Voltage<br>( $I_B = 0$ )            | $I_C = 200mA$ for <b>2N6386</b><br>for <b>2N6387</b><br>for <b>2N6388</b>   | 40<br>60<br>80             |      |                                  | V<br>V<br>V                      |
| $V_{CEr(sus)}^*$ | Collector-emitter Sustaining Voltage<br>( $R_{BE} = 100\Omega$ ) | $I_C = 200mA$ for <b>2N6386</b><br>for <b>2N6387</b><br>for <b>2N6388</b>   | 40<br>60<br>80             |      |                                  | V<br>V<br>V                      |
| $V_{CEV(sus)}^*$ | Collector-emitter Sustaining Voltage<br>( $V_{BE} = -1.5V$ )     | $I_C = 200mA$ for <b>2N6386</b><br>for <b>2N6387</b><br>for <b>2N6388</b>   | 40<br>60<br>80             |      |                                  | V<br>V<br>V                      |
| $V_{CE(sat)}^*$  | Collector-emitter Saturation Voltage                             | for <b>2N6386</b><br>$I_C = 3A$ $I_B = 6mA$<br>for <b>2N6387</b> and <b>2N6388</b><br>$I_C = 5A$ $I_B = 10mA$<br>for <b>2N6386</b><br>$I_C = 8A$ $I_B = 80mA$<br>for <b>2N6387</b> and <b>2N6388</b><br>$I_C = 10A$ $I_B = 100mA$                 |                            |      | 2<br>2<br>3<br>3                 | V<br>V<br>V<br>V                 |
| $V_{BE}^*$       | Base-emitter Voltage   | for <b>2N6386</b><br>$I_C = 3A$ $V_{CE} = 3V$<br>for <b>2N6387</b> and <b>2N6388</b><br>$I_C = 5A$ $V_{CE} = 3V$<br>for <b>2N6386</b><br>$I_C = 8A$ $V_{CE} = 3V$<br>for <b>2N6387</b> and <b>2N6388</b><br>$I_C = 10A$ $V_{CE} = 3V$             |                            |      | 2.8<br>2.8<br>4.5<br>4.5         | V<br>V<br>V<br>V                 |
| $h_{FE}^*$       | DC Current Gain  | for <b>2N6386</b><br>$I_C = 3A$ $V_{CE} = 3V$<br>for <b>2N6387</b> and <b>2N6388</b><br>$I_C = 5A$ $V_{CE} = 3V$<br>for <b>2N6386</b><br>$I_C = 8A$ $V_{CE} = 3V$<br>for <b>2N6387</b> and <b>2N6388</b><br>$I_C = 10A$ $V_{CE} = 3V$             | 1000<br>1000<br>100<br>100 |      | 20000<br>20000                   |                                  |

\* Pulsed : pulse duration = 300 $\mu$ s, duty cycle = 1.5%.

## ELECTRICAL CHARACTERISTICS (continued)

| Symbol         | Parameter                          | Test Conditions   | Min.       | Typ. | Max.   | Unit   |
|----------------|------------------------------------|---|------------|------|--------|--------|
| $h_{fe}$       | Small Signal Current Gain          | $I_C = 1A$<br>$V_{CE} = 10V$ $f = 1MHz$<br>$V_{CE} = 10V$ $f = 1KHz$                  | 20<br>1000 |      |        |        |
| $V_F^*$        | Paralleled-diode Forward Voltage   | for <b>2N6386</b><br>$I_F = 8A$<br>for <b>2N6387</b> and <b>2N6388</b><br>$I_F = 10A$ |            |      | 4<br>4 | V<br>V |
| $C_{CBO}$      | Collector-base Capacitance         | $I_E = 0$ $V_{CB} = 10V$<br>$f = 1MHz$  |            |      | 200    | pF     |
| $I_{s/b}^{**}$ | Second Breakdown Collector Current | $V_{CE} = 25V$  | 2.6        |      |        | A      |
| $E_{s/b}$      | Second Breakdown Energy            | $L = 12mH$ $R_{BE} = 100\Omega$<br>$V_{BE} = -1.5V$ $I_C = 4.5A$                      | 120        |      |        | mJ     |

\* Pulsed : pulse duration = 300 $\mu$ s, duty cycle = 1.5%.

\*\* Pulsed : 1s non repetitive pulse.

For characteristic curves see BDX33/BDX34 series.